

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









rfmd.com

# **SGA4363Z**

# DC to 4000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

Package: SOT-363

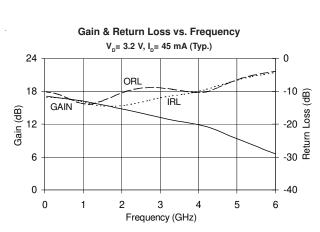




#### **Product Description**

The SGA4363Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high  $F_T$  and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.





#### **Features**

- High Gain: 14.8dB at 1950MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

#### **Applications**

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Davamatav	Specification			Heit	O and diking	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	15.5	17.5	19.0	dB	850MHz	
		14.8		dB	1950MHz	
		14.2		dB	2400MHz	
Output Power at 1dB Compression		14.3		dBm	850MHz	
		13.0		dBm	1950MHz	
Output Third Intercept Point		28.7		dBm	850 MHz	
		25.7		dBm	1950MHz	
Bandwidth Determined by Return Loss		4000		MHz	>9dB	
Input Return Loss		14.4		dB	1950MHz	
Output Return Loss		10.7		dB	1950MHz	
Noise Figure		3.1		dB	1950MHz	
Device Operating Voltage	2.9	3.2	3.5	V		
Device Operating Current	41	45	49	mA		
Thermal Resistance (Junction - Lead)		255		°C/W		

Test Conditions:  $V_S$  = 8V,  $I_D$  = 45 mA Typ., OIP $_3$  Tone Spacing = 1MHz,  $P_{OLIT}$  per tone = -5dBm,  $R_{BIAS}$  = 110 $\Omega$ ,  $T_L$  = 25 °C,  $Z_S$  =  $Z_L$  = 50 $\Omega$ 



#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Max Device Current (I <sub>D</sub> )	90	mA
Max Device Voltage (V <sub>D</sub> )	5	V
Max RF Input Power	+18	dBm
Max Junction Temp (T <sub>J</sub> )	+150	°C
Operating Temp Range (T <sub>L</sub> )	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

 $I_DV_D < (T_J - T_L) / R_{TH}$ , j-I



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device under Absolute Maximum Rating co

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

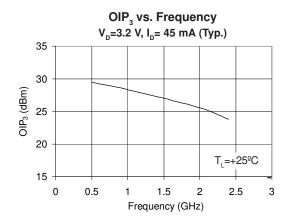


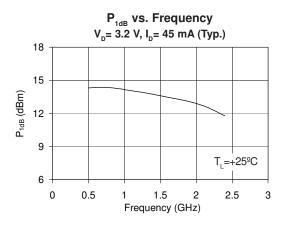
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in

#### Typical Performance at Key Operating Frequencies

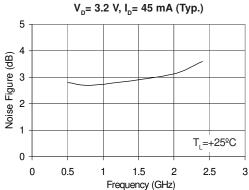
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	17.7	17.6	17.5	14.8	14.2	12.5
Output Third Order Intercept Point	dBm		29.4	28.7	25.7	23.8	
Output Power at 1dB Compression	dBm		14.3	14.3	13.0	11.8	
Input Return Loss	dB	11.9	12.2	12.9	14.4	13.6	11.0
Output Return Loss	dB	10.2	11.5	13.3	10.7	9.2	9.7
Reverse Isolation	dB	20.9	21.4	21.4	20.7	20.1	18.4
Noise Figure	dB		2.8	2.7	3.1	3.6	

Test Conditions:  $V_S = 8V$ ,  $I_D = 45$  mA Typ., OIP<sub>3</sub> Tone Spacing = 1MHz,  $P_{OUT}$  per tone = -5dBm,  $R_{BIAS} = 110\Omega$ ,  $T_L = 25$  °C,  $Z_S = Z_L = 50\Omega$ 



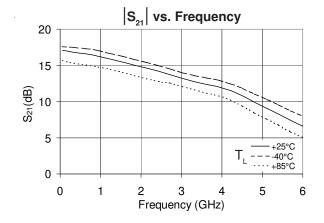


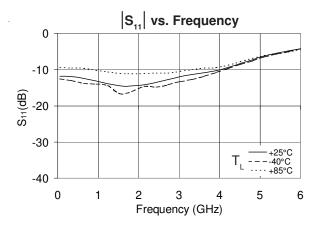
### Noise Figure vs. Frequency

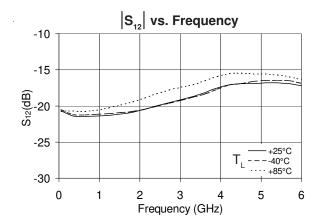


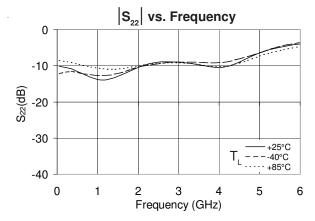


# Typical RF Performance Over Temperature ( Bias: $V_{\rm p}$ = 3.2 V, $I_{\rm p}$ = 45 mA (Typ.) )





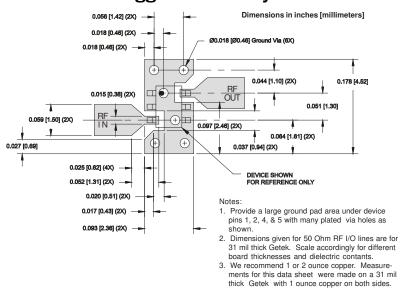






Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper operation.

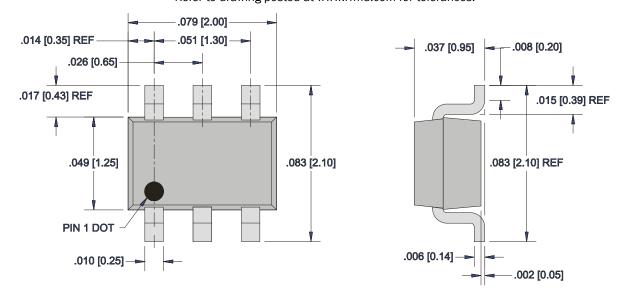
### **Suggested Pad Layout**



### **Package Drawing**

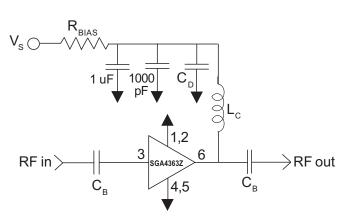
Dimensions in inches (millimeters)

Refer to drawing posted at www.rfmd.com for tolerances.





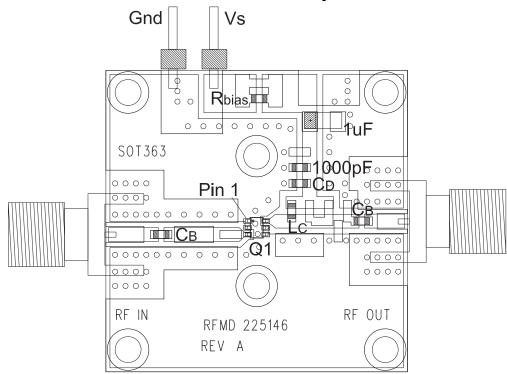
### **Application Schematic**



ı	Reference	Frequency (Mhz)						
ı	Designator	500	850	1950	2400	3500		
	Св	220 pF	100 pF	68 pF	56 pF	39 pF		
	$C_{D}$	100 pF	68 pF	22 pF	22 pF	15 pF		
	L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_D=45$ mA $R_{BIAS}=(V_S-V_D)/I_D$				
Supply Voltage(V <sub>s</sub> )	6 V	8 V	10 V	12 V
R <sub>BIAS</sub>	62 Ω	110 Ω	150 Ω	200 Ω
Note: R <sub>BIAS</sub> provides DC bias stability over temperature.				

### **Evaluation Board Layout**

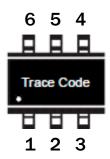


#### Mounting Instructions:

- 1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes, as shown.
- 2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce cooper on both sides.



### **Part Identification Marking**



# **Ordering Information**

Ordering Code	Description
SGA4363Z	7" Reel with 3000 pieces
SGA4363ZSQ	Sample bag with 25 pieces
SGA4363ZSR	7" Reel with 100 pieces
SGA4363ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag